## NSN 5961-01-463-5354

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-5354 **Inclosure Material:** Glass **Overall Length:** 1.197 inches **Terminal Length:** 0.825 inches **Overall Width:** 0.690 inches **End Application:** C-17aacfte/ifscm89954 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, instantaneous and 60.0 repetitive peak reverse voltage and 60.0 working peak reverse voltage **Current Rating Per Characteristic:** 45.00 amperes forward current, total rms megahertz and 320.00 amperes forward current, average preset and 1.00 amperes forward current, total rms torr **Capacitance Rating In Picofarads:** 2000.0 **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**